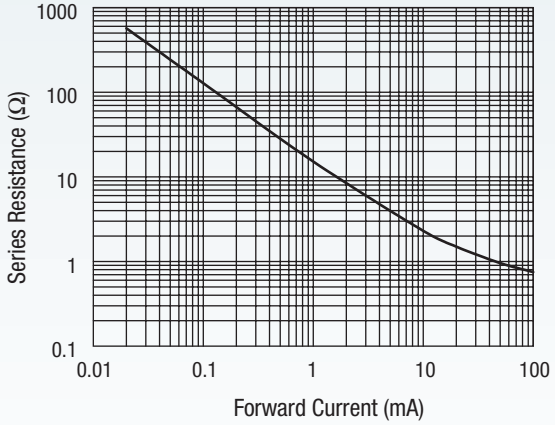
Operating Characteristics

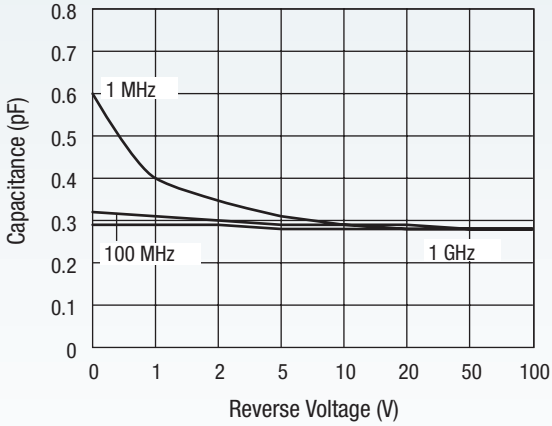
T = 25 °C, unless otherwise noted

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse current	I_R	V_R = 200 V			10	µA
Capacitance	C_{T30}	V_R = 30 V, f = 1 MHz			0.3	pF
Resistance	R_{S10}	I_F = 10 mA, f = 100 MHz			3	Ω
Resistance	R_{S100}	I_F = 100 mA, f = 100 MHz		1.0	1.5	Ω
Forward voltage	V_F	I_F = 10 mA		0.8		V
Carrier lifetime	T_L	I_F = 10 mA		700		ns
I-Region width	W			50		µm
CW thermal resistance	Θ_{JC}				40	°C/W
Pulse thermal resistance	Θ_P	Single 1 µs pulse		3.5		°C/W

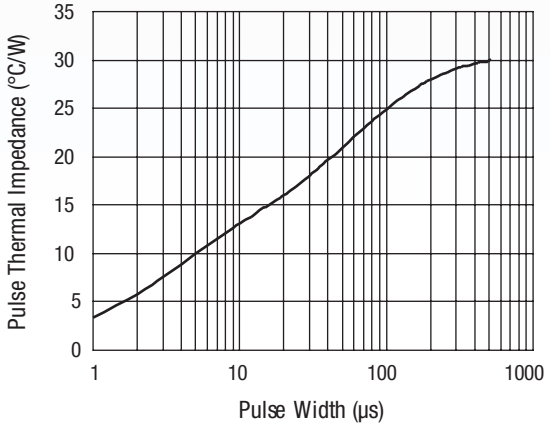
Typical Performance Data @ 25 °C, unless otherwise noted



Series Resistance vs. Current @ 100 MHz



Capacitance vs. Reverse Voltage



Typical Pulse Thermal Impedance

Absolute Maximum Ratings

Characteristic	Value
Reverse voltage	200 V
Forward current at 25 °C	1.5 A
CW power dissipation at 25 °C	3 W
1µs pulse power dissipation	30 W
Storage temperature range	-65 °C to +200 °C
Operating temperature range	-40 °C to +150 °C

Performance is guaranteed only under the conditions listed in the specifications table and is not guaranteed under the full range(s) described by the Absolute Maximum specifications. Exceeding any of the absolute maximum/minimum specifications may result in permanent damage to the device and will void the warranty.

T-R Switch Performance

Frequency	2010-2025 GHz
Insertion loss (Tx-ANT)	0.42 dB
Insertion loss (ANT-Rx)	0.45 dB
Isolation (Rx-Tx)	37 dB
Isolation (Tx-Rx)	37.8dB
0.1 dB Tx compression	46 dBm (Pulsed)
1.0 dB Tx compression	>50 dBm (Pulsed)
Tx-Rx IIP3	>80 dBm
Tx CW input power	41 dBm
Tx Peak input power[2]	>49.5 dBm
Rx CW input power	41 dBM
Tx-Rx switching speed[1]	<0.85 µs
Tx input return loss	27.8 dB
Rx input return loss	28.8 dB

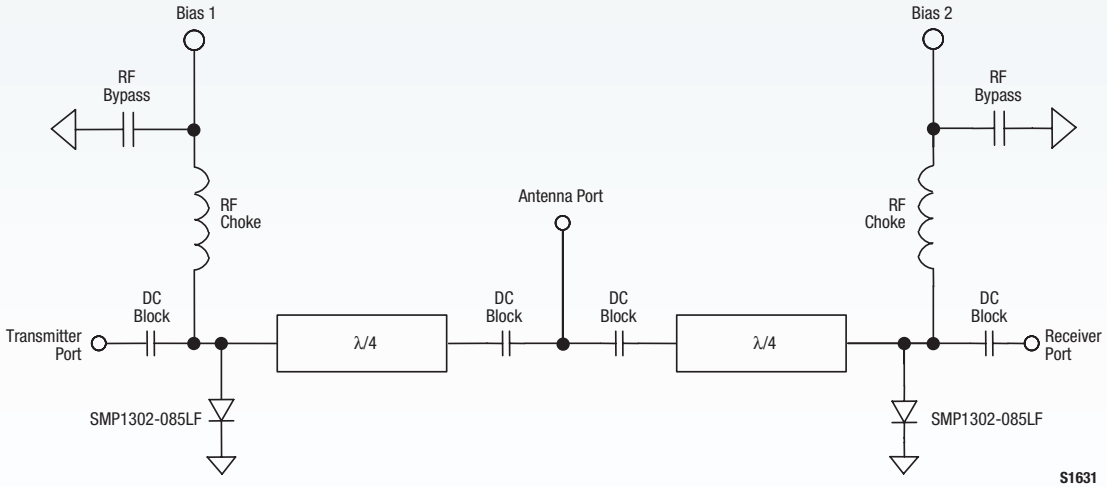
1. Based on complementary pulsed bias current waveforms under RF conditions.
2. Measured with 8 µs RF pulse width, 0.5% duty cycle, 50 Ω ANT load.
3. F1 = 2.0155 GHz @ 10 dBm, F2 = 2.0195 GHz @ 10 dBm.

High Power Switch Design Application

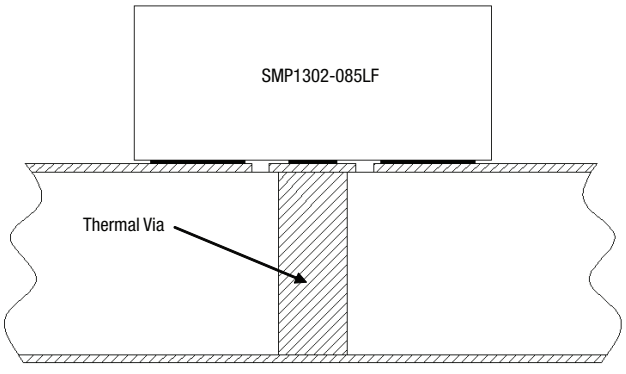
A T-R switch incorporating SMP1302 PIN diodes covering 2.0155 GHz to 2.0195 GHz has been designed and tested. The switch operated safely at transmitter power of 41dBm CW (12.6 W) with low insertion loss (0.42 dB) and high receiver isolation (37 dB). 1 dB compression occurred at higher than 50 dBm. In the receive state the switch performed with 0.45 dB insertion loss and 37.8 dB transmitter isolation.

The circuit is based on a quarter wave design utilizing two shunt connected SMP1302 diodes. In the transmit state the Bias 1 is set at 0 mA and Bias 2 is set at 50 mA; in the receive state Bias 1 is set at 50 mA and Bias 2 is set at 0 mA.

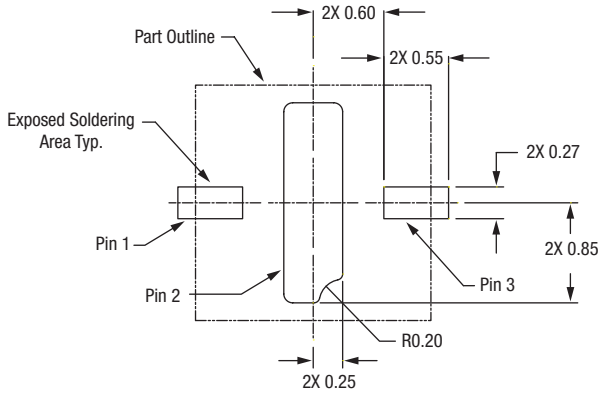
T-R Switch Circuit Diagram



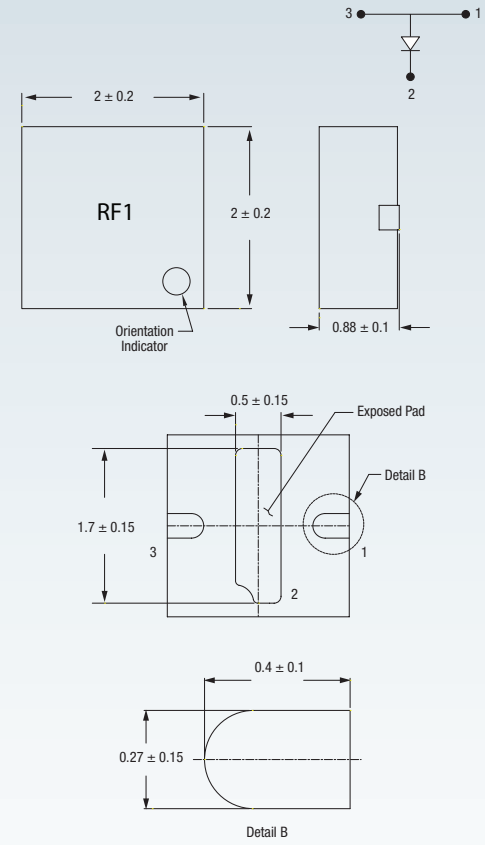
Microstrip Mount



Land Pattern



Outline Drawing



Note: Dimensions are in millimeters.

Application Notes

For additional information, please refer to the following Application Notes.

Solder Reflow Information

Discrete Devices and IC Switch/Attenuators Tape and Reel Package Orientation

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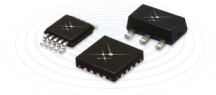

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